# imall

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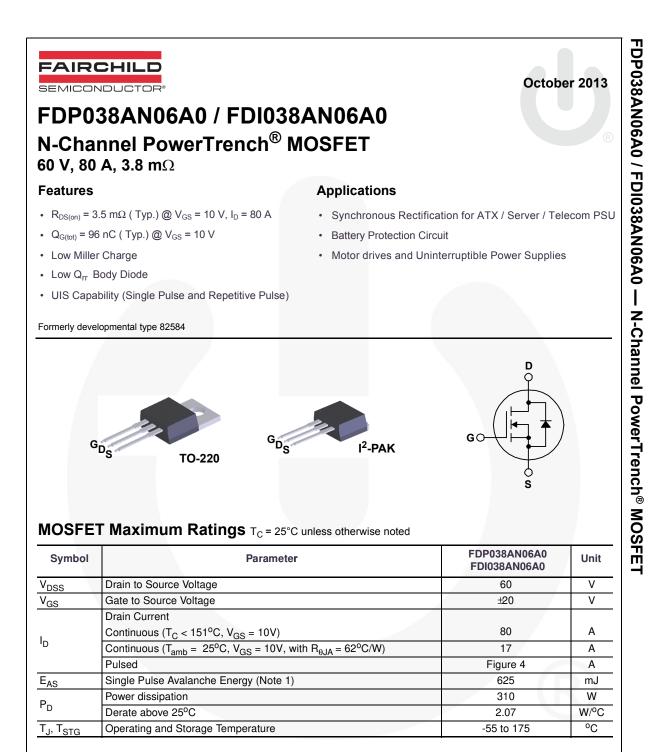
Is Now Part of



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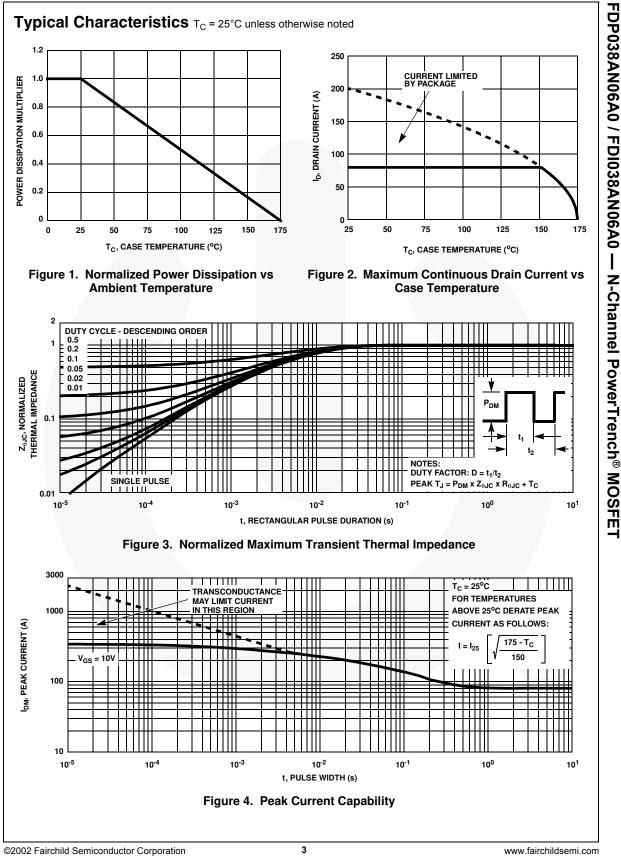
### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.48	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max. (Note 2)	62	°C/W

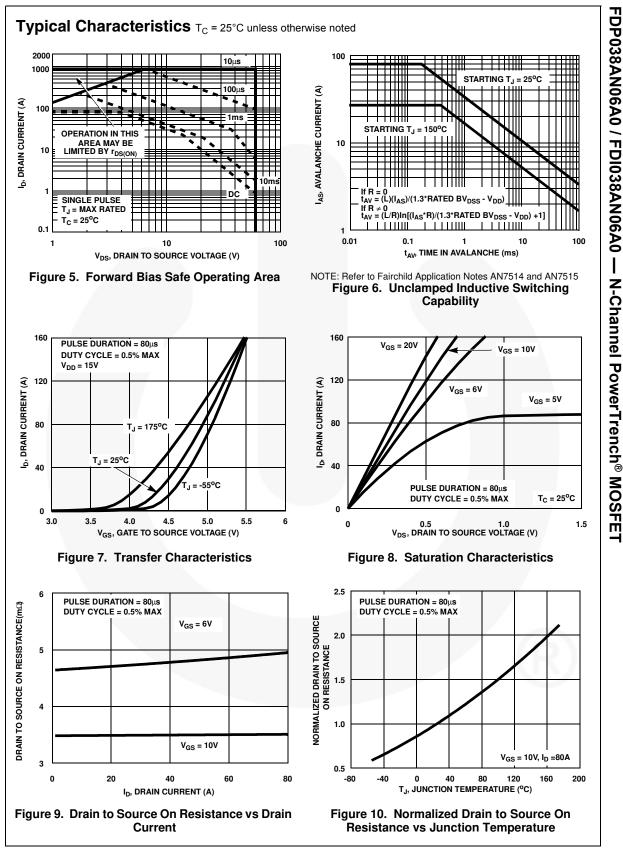
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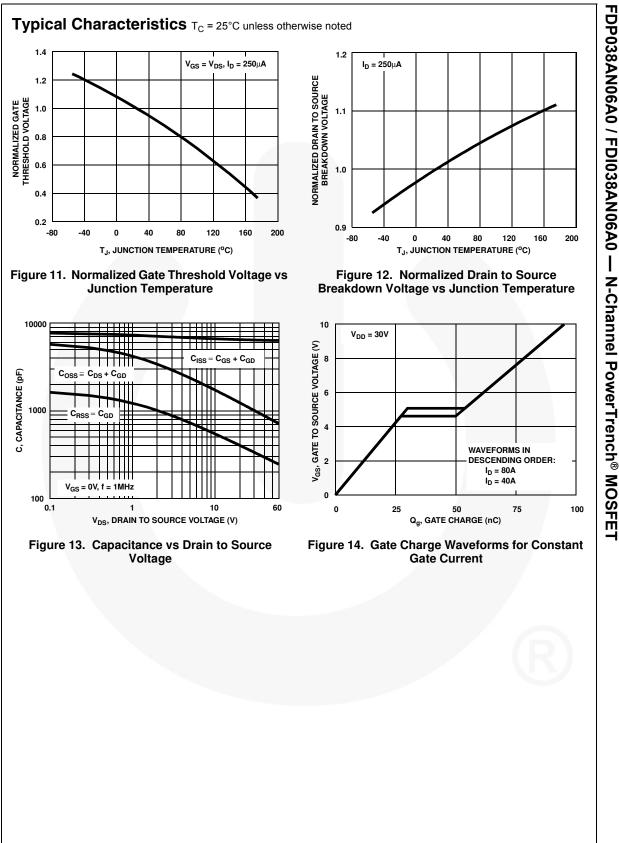
Device Marking FDP038AN06A0		Device	Package	Reel Size	Tape \	Nidth	Quantity	
		FDP038AN06A0	TO-220	Tube	N/A		50 units	
FDI038AN06A0 FDI038AN06A0		I <sup>2</sup> -PAK Tube		N/A		50 units		
		acteristics T <sub>C</sub> = 25°C	-					
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Unit
Off Chai	racteristic	s						
B <sub>VDSS</sub>	Drain to S	ource Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		60	-	-	V
			$V_{\rm DS} = 50V$		-	-	1	
IDSS	Zero Gate	e Voltage Drain Current	$V_{GS} = 0V$	$T_{C} = 150^{\circ}C$	-	-	250	μA
I <sub>GSS</sub>	Gate to S	ource Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Char	actoriatio							
	racteristic:				0			
V <sub>GS(TH)</sub>	Gate to S	ource Threshold Voltage	$V_{GS} = V_{DS},$		2	-	4	V
r <sub>DS(ON)</sub>			$I_{\rm D} = 80 {\rm A}, {\rm V}_{\rm C}$ $I_{\rm D} = 40 {\rm A}, {\rm V}_{\rm C}$		-	0.0035	0.0038	
	Drain to S	ource On Resistance			-	0.0049		Ω
			$T_{\rm J} = 00$ Å, $V_{\rm C}$	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, T <sub>1</sub> = 175°C		0.0071	0.0078	
			0			1	1	
	c Characte	eristics						
C <sub>ISS</sub>	Input Cap	acitance	V <sub>DS</sub> = 25V,		- \	6400	-	pF
C <sub>OSS</sub>		apacitance	$v_{DS} = 23 v$ , f = 1MHz	$\mathbf{v}_{\mathrm{GS}} = 0 \mathbf{v},$	-	1123	-	pF
C <sub>RSS</sub>	Reverse 1	ransfer Capacitance			-	367	-	pF
Q <sub>g(TOT)</sub>	Total Gate	e Charge at 10V	V <sub>GS</sub> = 0V to			96	124	nC
Q <sub>g(TH)</sub>		Gate Charge	V <sub>GS</sub> = 0V to	2V <sub>VDD</sub> = 30V	-	12	15	nC
Q <sub>gs</sub>		ource Gate Charge		I <sub>D</sub> = 80A	-	26	-	nC
Q <sub>gs2</sub>		rge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	15	-	nC
Q <sub>gd</sub>	Gate to D	rain "Miller" Charge			-	27	-	nC
Switchir	ng Charac	teristics (V <sub>GS</sub> = 10V)						
	Turn-On T						175	ns
t <sub>ON</sub> t <sub>d(ON)</sub>		Delay Time		 V <sub>DD</sub> = 30V, I <sub>D</sub> = 80A		17	-	ns
t <sub>r</sub>	Rise Time		Vaa - 30V			144	-	ns
t <sub>d(OFF)</sub>		, Delay Time	$V_{DD} = 30V,$ $V_{GS} = 10V,$	$R_{GS} = 2.4\Omega$	-	34	-	ns
t <sub>f</sub>	Fall Time			00	-	60	-	ns
t <sub>OFF</sub>	Turn-Off 1	īme			-	-	115	ns
						1		
Drain-So	ource Dioc	le Characteristics						
V <sub>SD</sub>	Source to	Drain Diode Voltage	I <sub>SD</sub> = 80A		-	-	1.25	V
• 50	Source to Drain Diode Voltage	I <sub>SD</sub> = 40A		-	-	1.0	V	
t <sub>rr</sub>		Recovery Time	-	ll <sub>SD</sub> /dt = 100A/μs	-	-	38	ns
Q <sub>RR</sub>	Reverse F	Recovered Charge	$I_{SD} = 75A$ , $dI_{SD}/dt = 100A/\mu s$		-	-	39	nC

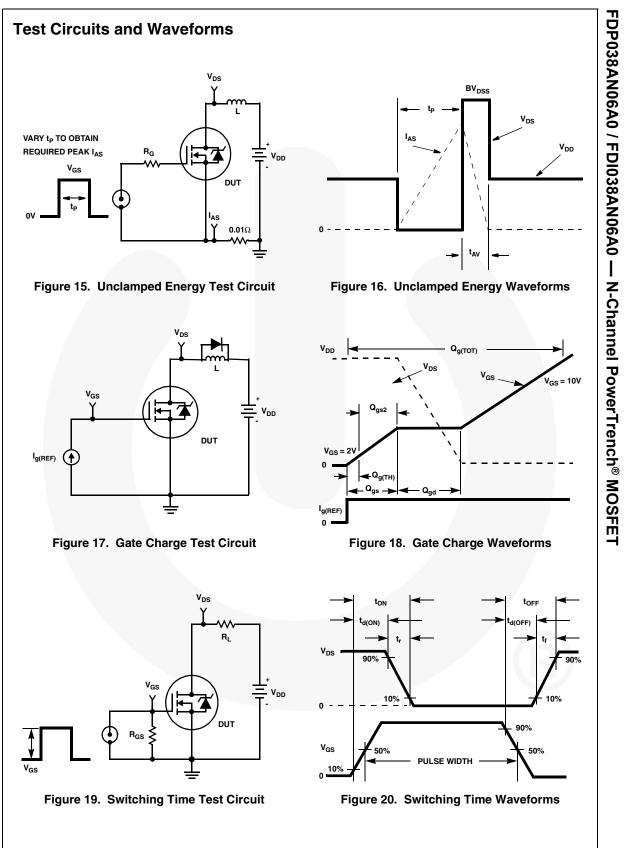


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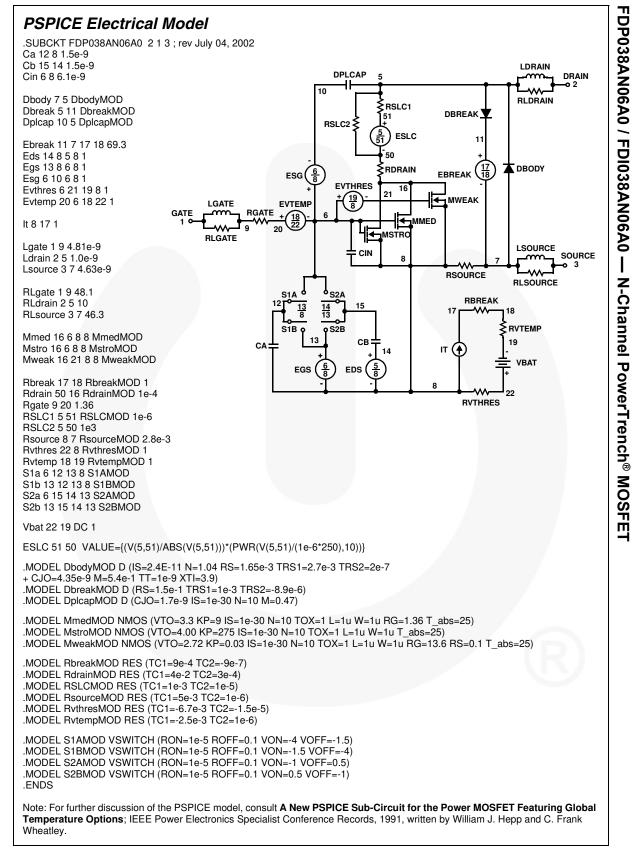


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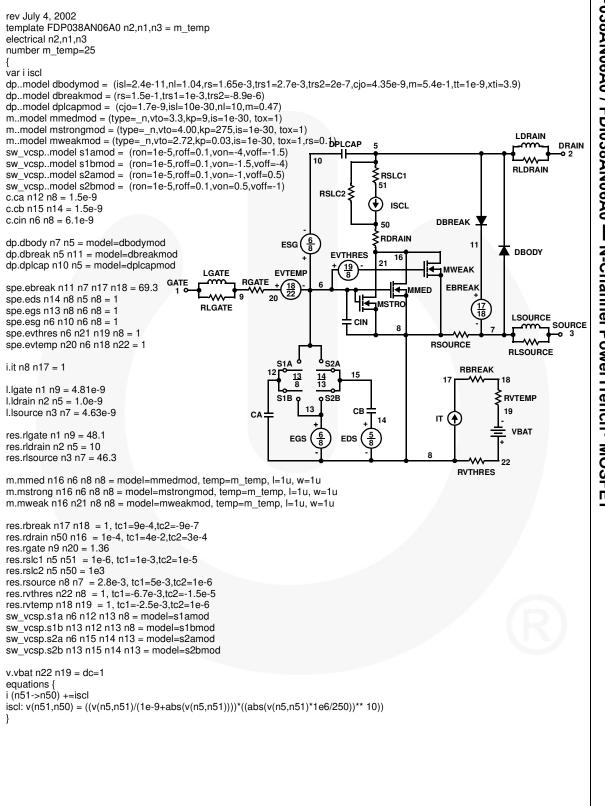
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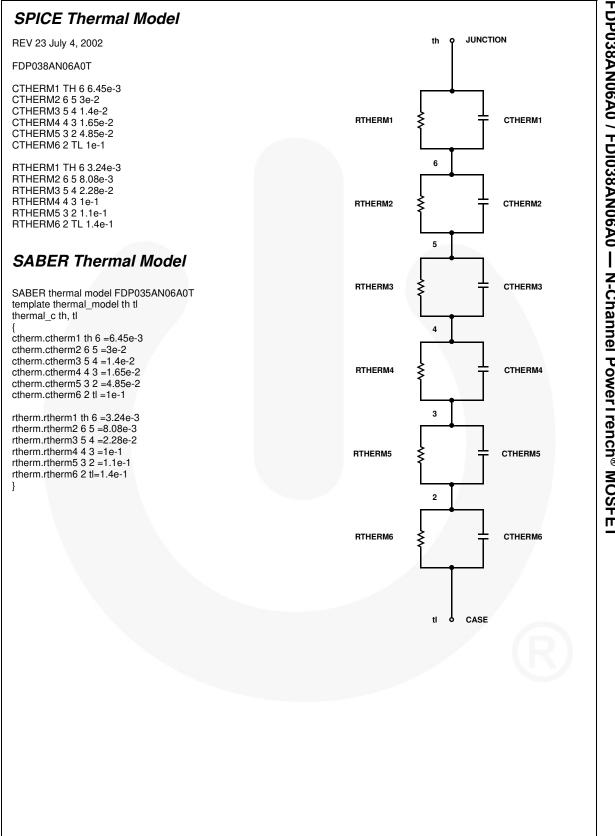
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### SABER Electrical Model

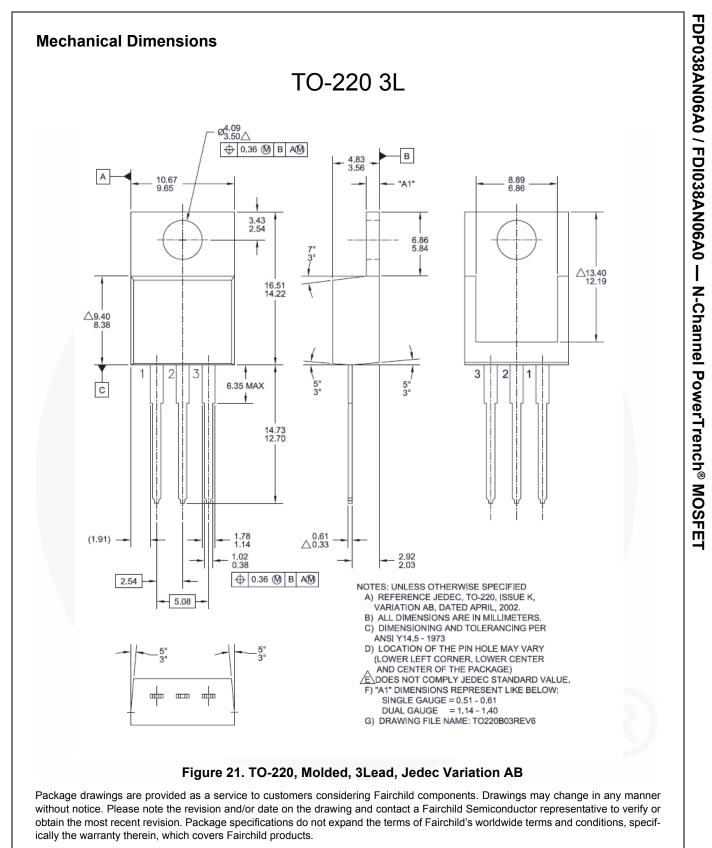


DP038AN06A0 / FDI038AN06A0 — N-Channel PowerTrench® MOSFET



# FDP038AN06A0 / FDI038AN06A0 — N-Channel PowerTrench® MOSFET

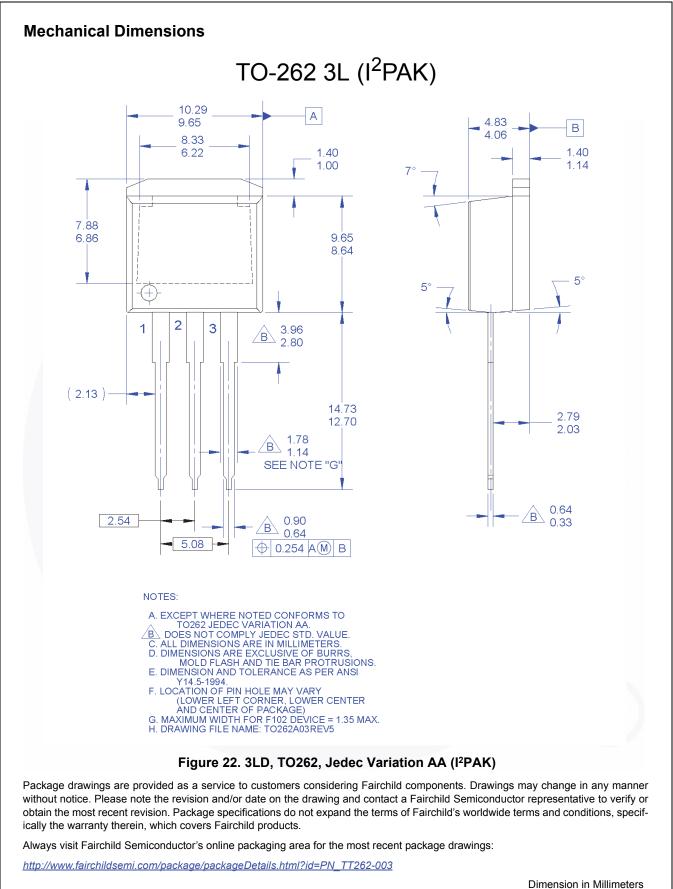
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**Dimension in Millimeters** 





No Identification Needed

Obsolete

Full Production

Not In Production

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